

MLP 4.5x5

MOSFET Maximum Ratings T_A = 25 °C unless otherwise noted

Symbol	Parameter			Ratings	Units	
V _{DS}	Drain to Source Voltage			100	V	
V _{GS}	Gate to Source Voltage			±20	V	
I _D	Drain Current -Continuous (Package limited) $T_C = 25 \text{ °C}$			6		
	-Continuous (Silicon limited)	T _C = 25 °C		9	•	
	-Continuous	T _A = 25 °C	(Note 1a)	3.1	Α	
	-Pulsed			12		
P _D	Power Dissipation	T _C = 25 °C		17	W	
	Power Dissipation $T_A = 25 \text{ °C}$ (Note 1a)		(Note 1a)	1.9	vv	
T _J , T _{STG}	Operating and Storage Junction Temperature Ra	inge		-55 to +150	°C	

Thermal Characteristics

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$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1a)	65	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1b)	135	C/VV

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDMQ8403	FDMQ8403	MLP 4.5x5	13 "	12 mm	3000 units

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FDMQ8403
N-Channel
PowerTrench
[®] MOSFET

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Chara	cteristics					
BV _{DSS}	Drain to Source Breakdown Voltage	I _D = 250 μA, V _{GS} = 0 V	100			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature	$I_D = 250 \ \mu$ A, referenced to 25 °C		72		mV/°C
IDSS	Zero Gate Voltage Drain Current	V _{DS} = 80 V, V _{GS} = 0 V			1	μA
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$			±100	nA
On Chara	cteristics					*
		V _{GS} = V _{DS} , I _D = 250 μA	2	2.8	4	V
V _{GS(th)}	Gate to Source Threshold Voltage Gate to Source Threshold Voltage		2	2.0	4	v
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Temperature Coefficient	$I_D = 250 \ \mu$ A, referenced to 25 °C		-8	110	mV/°C
_	Statia Durin ta Cauna On Dagistanaa	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 3 \text{ A}$		85	110	
r _{DS(on)}	Static Drain to Source On Resistance	$V_{GS} = 6 V, I_D = 2.4 A$		115 147	175	mΩ
0	Forward Transconductance	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 3 \text{ A}, \text{ T}_{J} = 125 \text{ °C}$ $V_{DS} = 10 \text{ V}, \text{ I}_{D} = 3 \text{ A}$		6	191	S
9fs	Forward Transconductance	$v_{\rm DS} = 10 v, i_{\rm D} = 3 {\rm A}$		0		3
Dynamic	Characteristics					
C _{iss}	Input Capacitance	1/2 = -50 / 1/2 = 0 / 1/2		162	215	pF
C _{oss}	Output Capacitance	──V _{DS} = 50 V, V _{GS} = 0 V, f = 1 MHz		43	60	pF
C _{rss}	Reverse Transfer Capacitance			2.6	5	pF
Switching	g Characteristics					
t _{d(on)}	Turn-On Delay Time			4.1	10	ns
t _r	Rise Time	V _{DD} = 50 V, I _D = 3 A,		1.2	10	ns
t _{d(off)}	Turn-Off Delay Time	$V_{GS} = 10 \text{ V}, \text{ R}_{GEN} = 6 \Omega$		7.2	15	ns
t _f	Fall Time			1.8	10	ns
Qg	Total Gate Charge	V _{GS} = 0 V to 10 V		3	5	nC
Q _g	Total Gate Charge	$V_{GS} = 0 V \text{ to } 5 V$ $V_{DD} = 50 V.$		1.7	3	nC
Q _{gs}	Gate to Source Charge	$I_D = 3 A$		0.9		nC
Q _{gd}	Gate to Drain "Miller" Charge			0.8		nC
Drain-Sou	arce Diode Characteristics					
V _{SD}	Source to Drain Diode Forward Voltage	$V_{GS} = 0 V, I_S = 3 A$ (Note 2)		0.86	1.3	V
t _{rr}	Reverse Recovery Time			33	53	ns
Q _{rr}	Reverse Recovery Charge	$-I_F = 3 \text{ A}, \text{ di/dt} = 100 \text{ A/}\mu\text{s}$		23	37	nC
Notes: 1. R _{θJA} is determ	ined with the device mounted on a 1in ² pad 2 oz copper pad	d on a 1.5 x 1.5 in. board of FR-4 material. $R_{ ext{ heta}JC}$ is (guaranteed b	oy design wh	ile R _{θCA} is de	etermined b
the user's boar	a. 65 °C/W when mounted on pad of 2 oz copper. the			ounted on a 2 oz copper		
	designed Q1+Q3 or Q2+Q4		ard designe	d Q1+Q3 o		
	00000					
2. Pulse Test: Pu	llse Width < 300 $\mu s,$ Duty cycle < 2.0%.					

Electrical Characteristics $T_J = 25$ °C unless otherwise noted



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